

## N-Channel 16-V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ.)
16	0.003 at $V_{GS} = 4.5$ V	29	54
	0.0055 at $V_{GS} = 2.5$ V	23	

### FEATURES

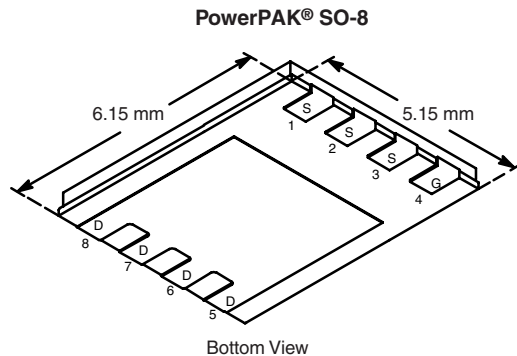
- Halogen-free available
- TrenchFET® Power MOSFETS: 2.5 V Rated
- Low 3.3 m $\Omega$   $R_{DS(on)}$
- Low Gate Resistance
- 100 %  $R_g$  Tested



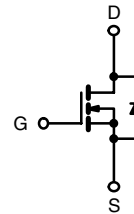
**RoHS**  
COMPLIANT

### APPLICATIONS

- Synchronous Rectification
- Low Output Voltage Synchronous Rectification



**Ordering Information:** Si7862ADP-T1-E3 (Lead (Pb)-free)  
Si7862ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	10 s	Steady State	Unit
Drain-Source Voltage	$V_{DS}$	16		V
Gate-Source Voltage	$V_{GS}$	$\pm 8$		
Continuous Drain Current ( $T_J = 150$ °C) <sup>a</sup>	$I_D$	29	18	A
		23	14	
Pulsed Drain Current (10 $\mu$ s Pulse Width)	$I_{DM}$	60		
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	4.5	1.6	
Maximum Power Dissipation <sup>a</sup>	$P_D$	5.4	1.9	W
		3.4	1.2	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>		260		

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	18	23	°C/W
		50	65	
Maximum Junction-to-Case (Drain)	$R_{thJC}$	1.0	1.5	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<http://www.vishay.com/ppg?73257>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

**SPECIFICATIONS**  $T_J = 25^\circ\text{C}$ , unless otherwise noted

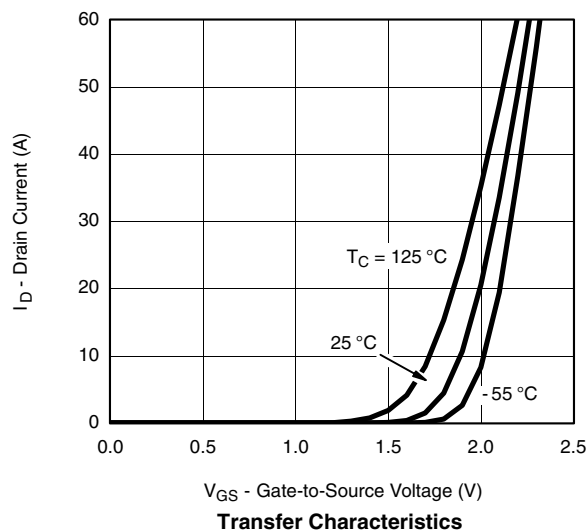
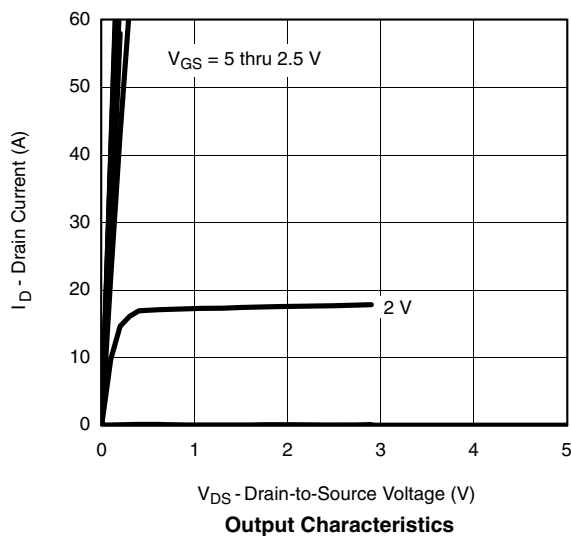
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\ \mu\text{A}$	0.6		2.0	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\ \text{V}$ , $V_{GS} = \pm 8\ \text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 16\ \text{V}$ , $V_{GS} = 0\ \text{V}$			1	$\mu\text{A}$
		$V_{DS} = 16\ \text{V}$ , $V_{GS} = 0\ \text{V}$ , $T_J = 55^\circ\text{C}$			5	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5\ \text{V}$ , $V_{GS} = 4.5\ \text{V}$	30			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 4.5\ \text{V}$ , $I_D = 29\ \text{A}$		0.0024	0.003	$\Omega$
		$V_{GS} = 2.5\ \text{V}$ , $I_D = 23\ \text{A}$		0.0045	0.0055	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 6\ \text{V}$ , $I_D = 29\ \text{A}$		140		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 4.5\ \text{A}$ , $V_{GS} = 0\ \text{V}$		0.75	1.2	V
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 8\ \text{V}$ , $V_{SS} = 0\ \text{V}$ , $f = 1\ \text{MHz}$		7340		pF
Output Capacitance	$C_{oss}$			2180		
Reverse Transfer Capacitance	$C_{rss}$			945		
Total Gate Charge	$Q_g$	$V_{DS} = 6\ \text{V}$ , $V_{GS} = 4.5\ \text{V}$ , $I_D = 29\ \text{A}$		54	80	nC
Gate-Source Charge	$Q_{gs}$			11.5		
Gate-Drain Charge	$Q_{gd}$			12.5		
Gate Resistance	$R_g$		0.5	1.1	1.8	$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 6\ \text{V}$ , $R_L = 6\ \Omega$ $I_D \cong 1\ \text{A}$ , $V_{GEN} = 4.5\ \text{V}$ , $R_G = 6\ \Omega$		42	60	ns
Rise Time	$t_r$			38	60	
Turn-Off Delay Time	$t_{d(off)}$			120	180	
Fall Time	$t_f$			50	75	
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = 2.9\ \text{A}$ , $di/dt = 100\ \text{A}/\mu\text{s}$		80	120	

Notes:

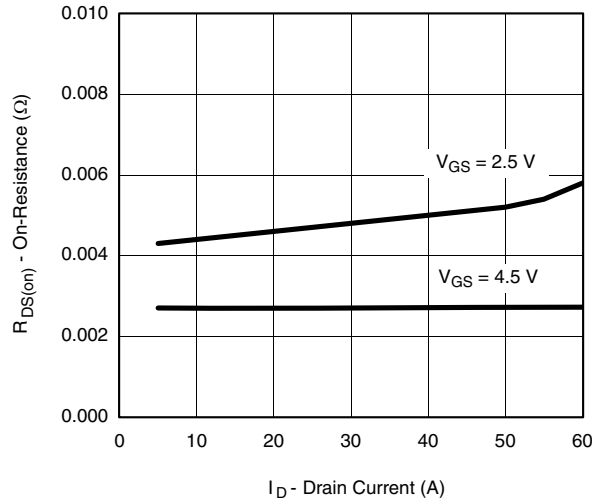
a. Pulse test; pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$ .

b. Guaranteed by design, not subject to production testing.

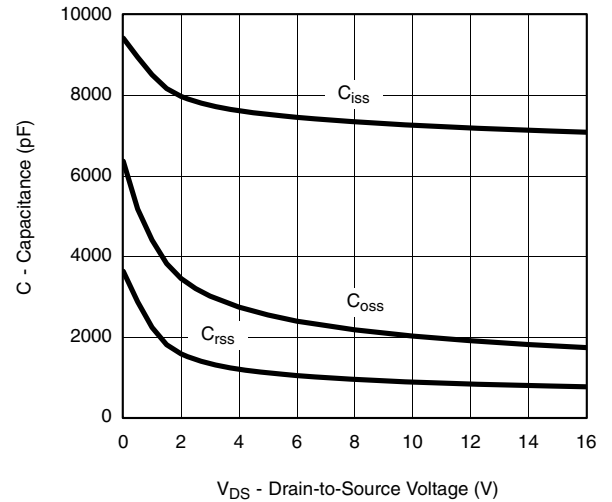
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS**  $25^\circ\text{C}$ , unless otherwise noted

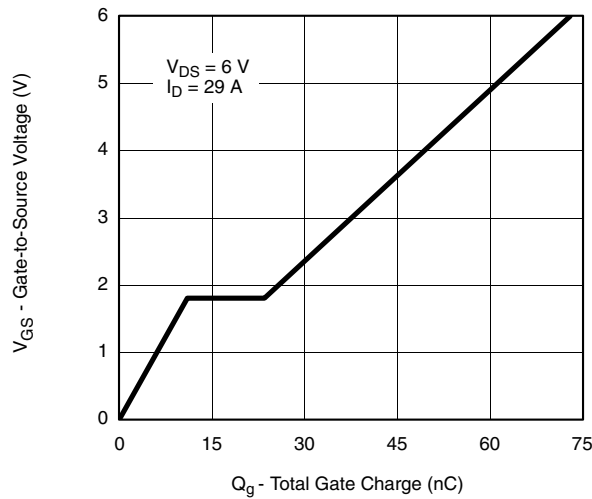
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



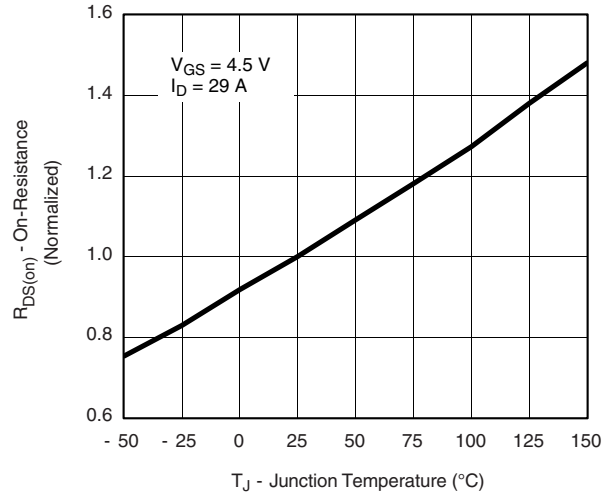
On-Resistance vs. Drain Current



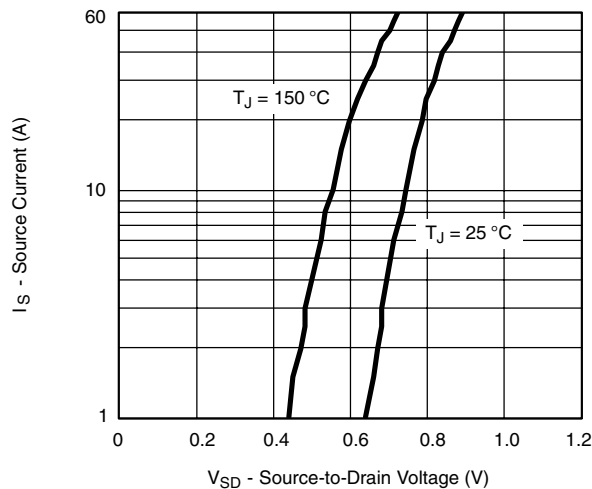
Capacitance



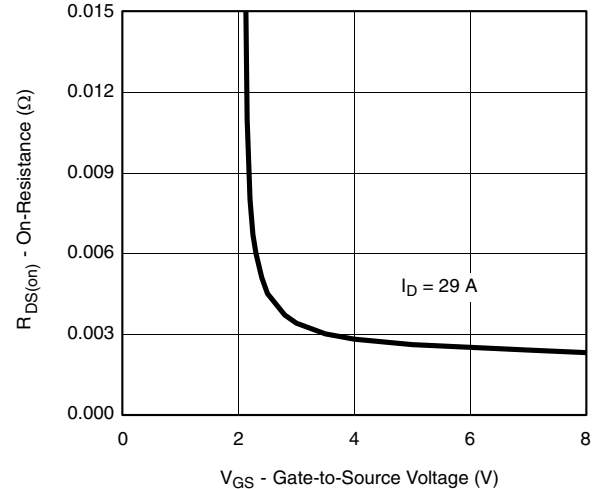
Gate Charge



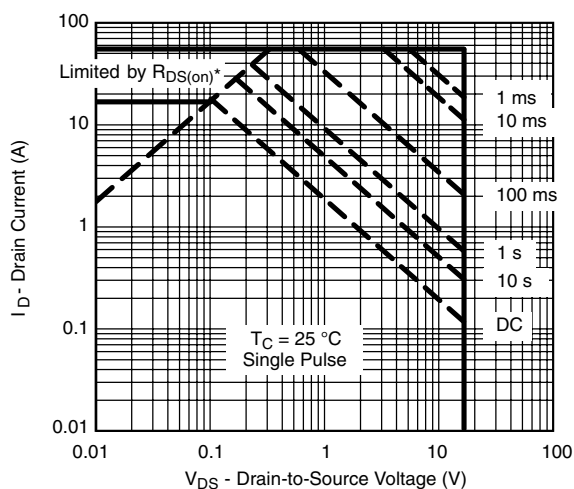
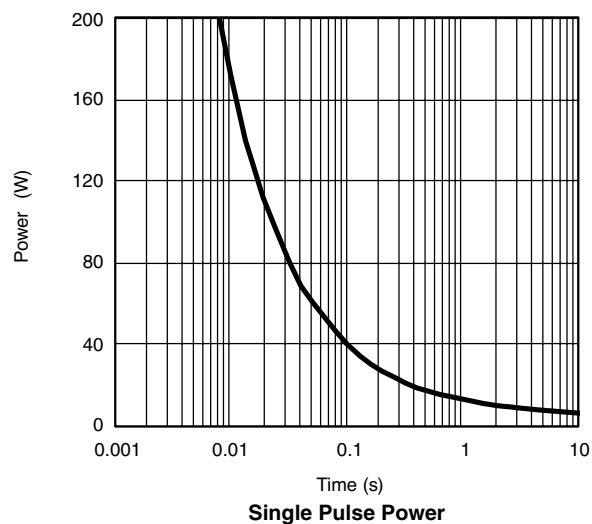
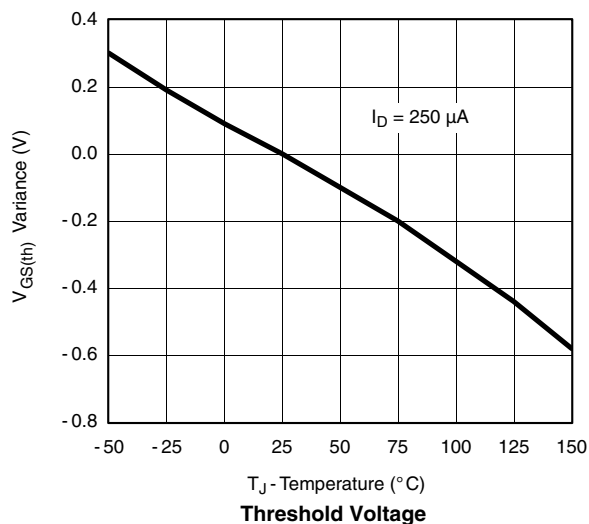
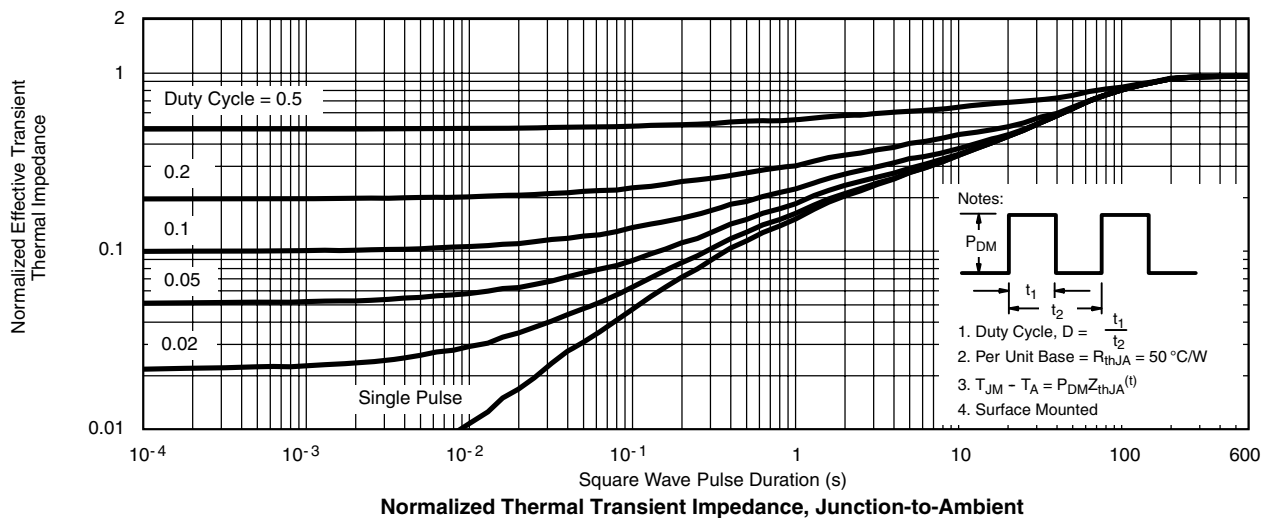
On-Resistance vs. Junction Temperature



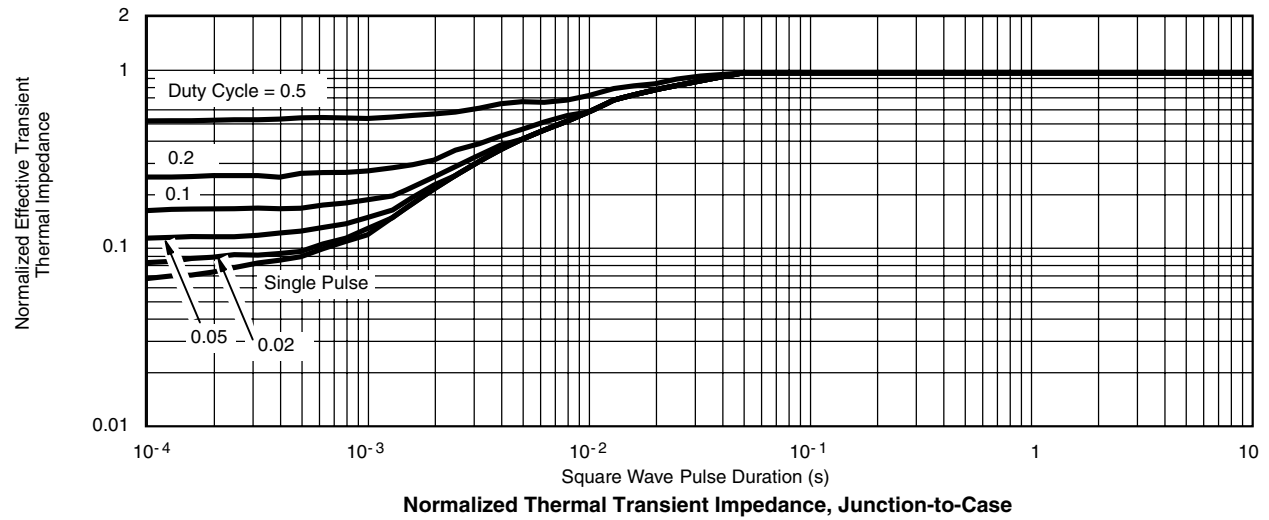
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified**Safe Operating Area Junction-to-Case**

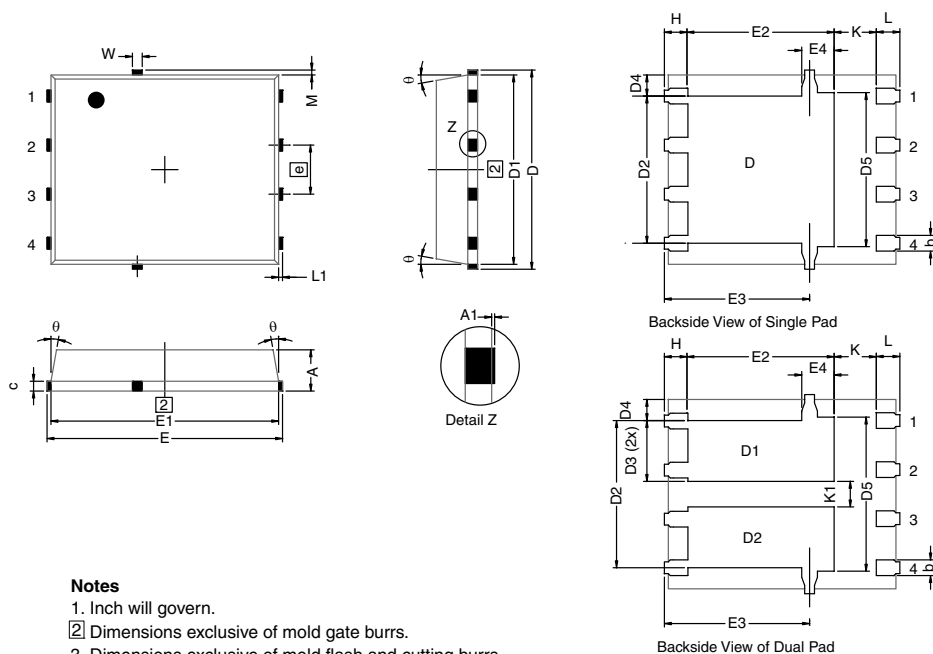
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?73165>.

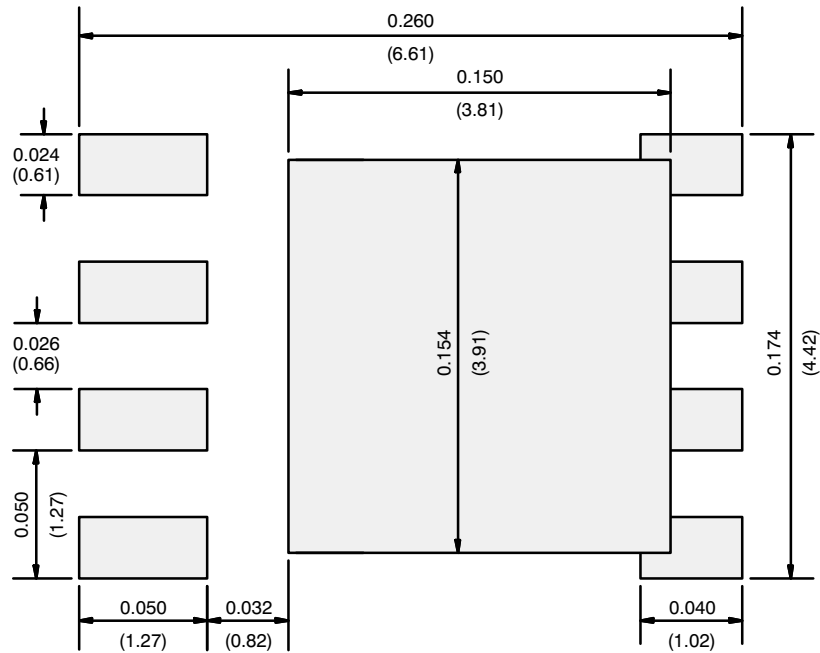


## PowerPAK® SO-8, (Single/Dual)



DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.97	1.04	1.12	0.038	0.041	0.044
A1		-	0.05	0	-	0.002
b	0.33	0.41	0.51	0.013	0.016	0.020
c	0.23	0.28	0.33	0.009	0.011	0.013
D	5.05	5.15	5.26	0.199	0.203	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.56	3.76	3.91	0.140	0.148	0.154
D3	1.32	1.50	1.68	0.052	0.059	0.066
D4	0.57 typ.			0.0225 typ.		
D5	3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	5.79	5.89	5.99	0.228	0.232	0.236
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151
E3	3.68	3.78	3.91	0.145	0.149	0.154
E4 (for AL product)	0.58 typ.			0.023 typ.		
E4 (for other product)	0.75 typ.			0.030 typ.		
e	1.27 BSC			0.050 BSC		
K (for AL product)	1.45 typ.			0.057 typ.		
K (for other product)	1.27 typ.			0.050 typ.		
K1	0.56	-	-	0.022	-	-
H	0.51	0.61	0.71	0.020	0.024	0.028
L	0.51	0.61	0.71	0.020	0.024	0.028
L1	0.06	0.13	0.20	0.002	0.005	0.008
θ	0°	-	12°	0°	-	12°
W	0.15	0.25	0.36	0.006	0.010	0.014
M	0.125 typ.			0.005 typ.		
ECN: C13-0702-Rev. K, 20-May-13						
DWG: 5881						

## RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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